

KS05VL4-C

60W, 5V Ultra Low Capacitance ESD Protection Array

RoHS Compliant Product
A suffix of "-C" specifies halogen and lead-free

FEATURES

KS05VL4-C is an ultra-low capacitance TVS designed to protection for high-speed data interfaces. With typical capacitance of 0.2pF (I/O to I/O) only, it is designed to protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD) Level 4, IEC 61000-4-4 (EFT), very fast charged device model (CDM) ESD and cable discharge event (CDE) etc.

The combined features of ultra-low capacitance, small size and high ESD robustness make it ideal for high-speed data ports and high-frequency lines applications. The low clamping voltage of the KS05VL4-C guarantees a minimum stress on the protected IC.

FEATURES

- Transient Protection for High-Speed Data Lines
- Package Optimized for High-Speed Lines
- Protects four Data Lines and One V_{CC} Line
- Low Capacitance and Clamping Voltage
- Low Leakage Current
- Flammability Rating: UL 94V-0

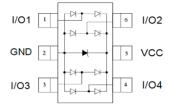
MARKING

Y B05

V05

TSOP-6





PACKAGE INFORMATION

Package	MPQ	Leader Size
TSOP-6	3K	7 inch

ORDER INFORMATION

Part Number	Туре
KS05VL4-C	Lead (Pb)-free and Halogen-free

ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise specified)

Parameter		Symbol	Ratings	Unit	
IEC 61000-4-2 ESD Voltage	Air Model	V _{ESD}	±25	101	
	Contact Model		±20	KV	
Peak Pulse Power @tp=8/20µs		P _{PP}	60	W	
Peak Pulse Current @tp=8/20µs		I _{PP}	4	А	
Operating Junction Temperature Range		TJ	-55~125	200	
Storage Temperature Range		Tstg	-55~150	- °C	

http://www.SeCoSGmbH.com/

Any changes of specification will not be informed individually.

25-May-2023 Rev. D Page 1 of 3



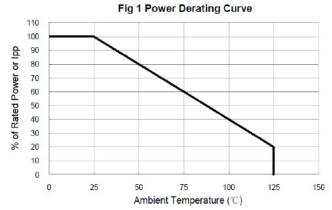
KS05VL4-C

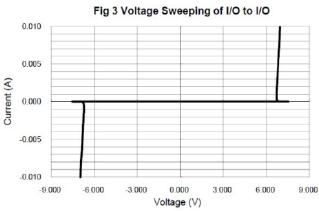
60W, 5V Ultra Low Capacitance ESD Protection Array

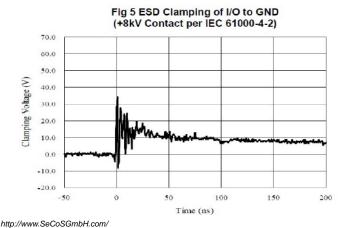
ELECTRICAL CHARACTERISTICS (T_A=25°C unless otherwise specified)

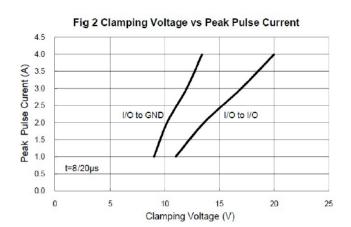
Parameter	Symbol	Min.	Тур.	Max.	Unit	Test Conditions
Reverse Working Voltage	V _{RWM}	-	-	5	V	I/O to GND
Reverse Breakdown Voltage	V_{BR}	6	-	9	V	I _T =1mA, I/O to GND
Reverse Leakage Current	I _R	-	-	1	μΑ	V _{RWM} =5V, I/O to GND
Surge Clamping Voltage @tp=8/20µs		-	-	10	V	I _{PP} =1A, I/O to GND
	Vc	-	-	15		IPP=4A, I/O to GND
		-	-	15		IPP=8A, VCC to GND
Junction Capacitance @V _R =0V, f=1MHz		-	0.2	0.3	pF	Between I/O Pins
	C₁	-	0.45	0.5		Between I/O and GND
		-	0.8	-		Between Vcc and GND

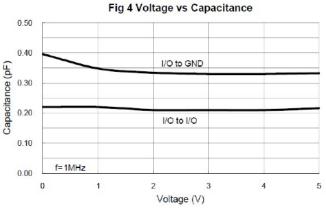
RATINGS AND CHARACTERISTICS CURVES

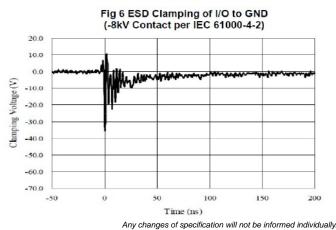












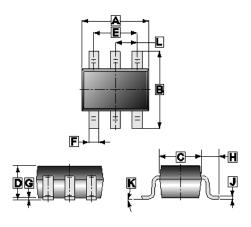


KS05VL4-C

60W, 5V Ultra Low Capacitance ESD Protection Array

PACKAGE OUTLINE DIMENSIONS

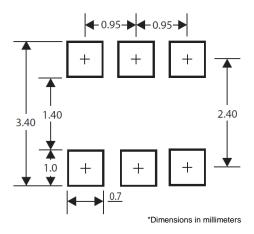
TSOP-6



REF.	Millimeter			
	Min.	Max.		
Α	2.70	3.10		
В	2.60	3.00		
С	1.40	1.80		
D	-	1.45		
Е	1.90 REF.			
F	0.30	0.50		
G	0	0.10		
Η	0.60 REF.			
J	0.12 REF.			
K	0°	10°		
L	0.95 REF.			

MOUNTING PAD LAYOUT

TSOP-6



http://www.SeCoSGmbH.com/ 25-May-2023 Rev. D Any changes of specification will not be informed individually.